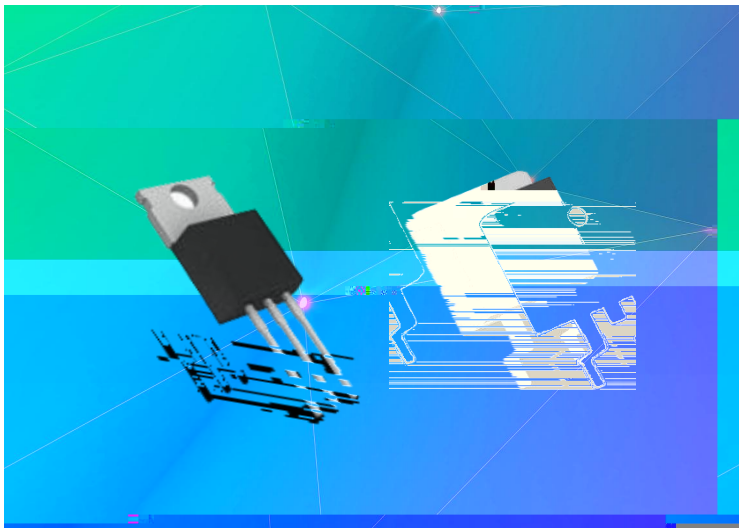


微沟



TO-220/TO-263

650V IGBT

1.

650V

50A@Tc=100

3.

4.

Icm

300A



| Product Name  | V <sub>CES</sub> (V) | I <sub>c</sub> (A) | V <sub>GE(th)</sub> (V) | V <sub>CE(sat)</sub> (V) | V <sub>F</sub> (V) | P <sub>d</sub> (W) | T <sub>j</sub> |
|---------------|----------------------|--------------------|-------------------------|--------------------------|--------------------|--------------------|----------------|
| DGP50N65ATS2A | 650V                 | 50A                | 4.8                     | 1.4                      | -                  | 283                | -40~175        |
| DGB50N65ATS2A | 650V                 | 50A                | 4.8                     | 1.4                      | -                  | 283                | -40~175        |



1. Micro-trench process platform, a highly cost-a

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New Product Announcement